

Schottky Barrier Rectifier

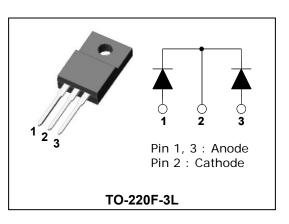
DUAL COMMON CATHODE SCHOTTKY RECTIFIER

Features

- Low forward voltage drop
- Low power loss and High efficiency
- Low leakage current
- High surge capacity
- Full lead (Pb)-free and RoHS compliant device

Applications

- High efficiency SMPS
- Output rectification
- High frequency switching
- Freewheeling
- DC-DC converter systems



Product Characteristics

I _{F(AV)}	2 X 10A
V _{RRM}	60V
V _{FM} at 125℃	0.55V
I _{FSM}	150A

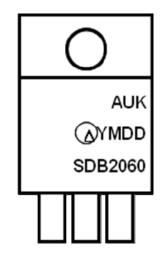
Description

The SDB2060PI is suited for Switch Mode Power Supply and high frequency DC to DC converters. This device is especially intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.

Ordering Information

Device	Marking Code	Package	Packaging
SDB2060PI	SDB2060PI SDB2060		Tube

Marking Information



AUK = Manufacture Logo Δ = Control Code of Manufacture

YMDD = Date Code Marking

- -. Y = Year Code
- -. M = Monthly Code
- -. D = Daily Code

SDB2060 = Specific Device Code

Absolute Maximum Ratings (Limiting Values)

Characteristic		Symbol	Value	Unit	
Maximum repetitive reverse voltage Maximum working peak reverse voltage Maximum DC blocking voltage		V _{rrm} V _{rwm} V _r	60	V	
Maximum average forward rectified current	per diode		10	A	
	total device	I _{F(AV)}	20		
Peak forward surge current 8.3ms single half sine-wave superimposed on rated load per diode		I _{FSM}	150	A	
Storage temperature range		T _{stg}	-55 to +150	°C	
Maximum operating junction temperature		Tj	150		

Thermal Characteristics

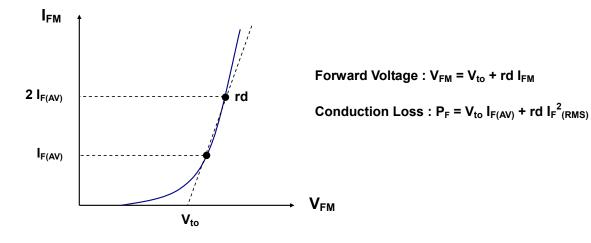
Characteristic		Symbol	Value	Unit
Maximum thermal resistance junction to case	per diode	D	4.0	°C/W
	total device	R _{th(j-c)}	3.6	

Electrical Characteristics

Characteristic	Symbol	Test Condition		Min.	Тур.	Max.	Unit			
Peak forward voltage drop	forward voltage drop $V_{FM}^{(1)}$ $I_{FM} = 10A$	I _{FM} = 10A	Tj =25 ℃	-	0.55	0.65	v			
Feak loi ward vollage drop	¥ FM	IFM = TUA	Tj=125℃	-	0.50	0.55				
	I _{RM}					Tj =25 ℃	-	-	1.5	m 4
Reverse leakage current		$V_{R} = V_{RRM}$	Tj=125℃	-	-	200	mA			
Junction capacitance	C _j	$V_{R} = 4V_{DC}$, f=1MHz		-	400	-	pF			

Note : (1) Pulse test : $t_{P}\!\leq\!380us,$ Duty cycle $\leq\!2\%$

To evaluate the conduction losses use the following equation: $P_F = 0.35 I_{F(AV)} + 0.019 I_{F}^{2}_{(RMS)}$



Rating and Characteristic Curves

Fig. 1) Typical Forward Characteristics (Per Diode)

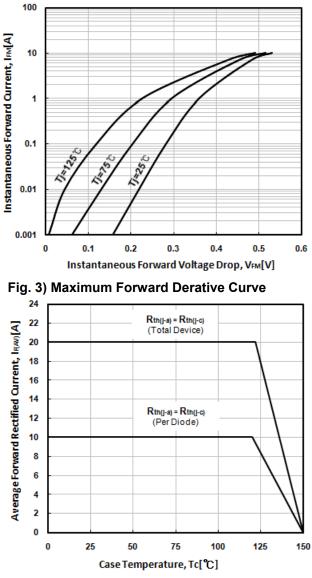


Fig. 5) Maximum Non-Repetitive Peak Forward Surge Current (Per Diode)

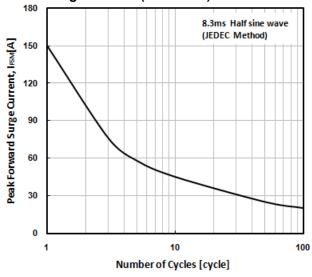


Fig. 2) Typical Reverse Characteristics (Per Diode)

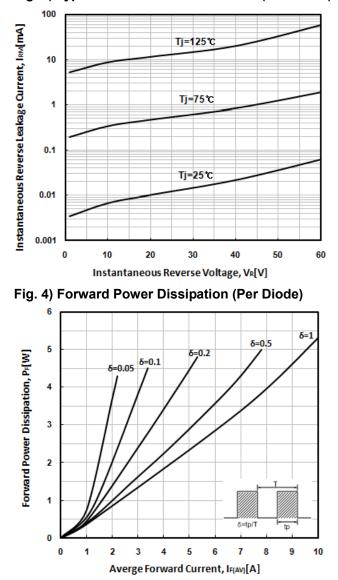
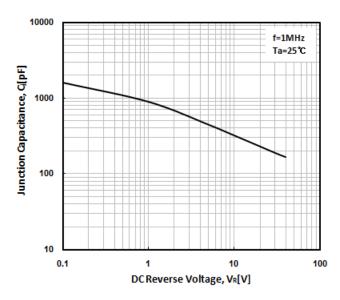


Fig. 6) Typical Junction Capacitance (Per Diode)



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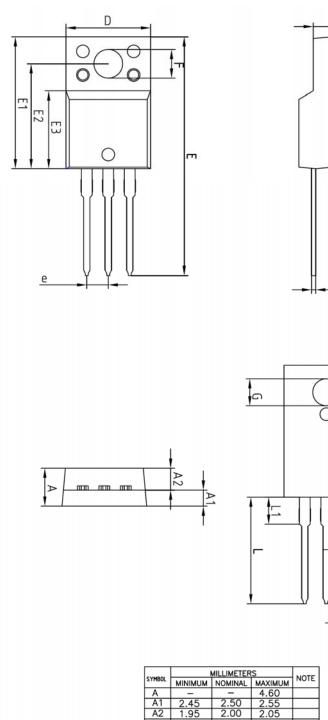
C1

С

Ь1

Ь

Package Outline Dimension (Unit : mm)



b

b1

G

е

1.1

0.6

<u>9.15</u> 3.30

3.10

12.40

2.00	2.05	
0.75	0.85	
1.27	1.47	
0.50	0.60	
2.80	2.90	
10.00	10.10	
-	28.60	
15.60	15.70	
12.40	12.50	
9.20	9.25	
3.40	3.50	
3.20	3.30	

13.0

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